

Low-Voltage CMOS Octal Buffer

With 5 V-Tolerant Inputs and Outputs
(3-State, Inverting)

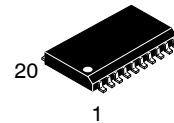
MC74LCX240

The MC74LCX240 is a high performance, inverting octal buffer operating from a 1.65 to 5.5 V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5 V allows MC74LCX240 inputs to be safely driven from 5 V devices. The MC74LCX240 is suitable for memory address driving and all TTL level bus oriented transceiver applications.

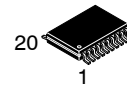
Current drive capability is 24 mA at the outputs at 3 V. The Output Enable (\overline{OE}) input, when HIGH, disables the outputs by placing them in a HIGH Z condition.

Features

- Designed for 1.65 to 5.5 V V_{CC} Operation
- 5 V Tolerant – Interface Capability With 5 V TTL Logic
- Supports Live Insertion and Withdrawal
- I_{OFF} Specification Guarantees High Impedance When $V_{CC} = 0$ V
- LVTTTL Compatible
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability at 3 V
- Near Zero Static Supply Current in All Three Logic States (10 μ A)
Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 100 mA
- ESD Performance:
 - ♦ Human Body Model >2000 V
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

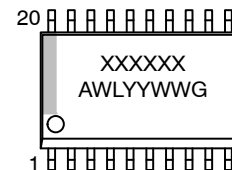


SOIC-20 WB
DW SUFFIX
CASE 751D

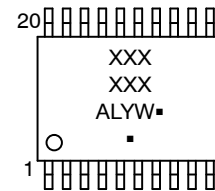


TSSOP-20
DT SUFFIX
CASE 948E

MARKING DIAGRAM



SOIC-20 WB



TSSOP-20

A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week
G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information on page 7 of this data sheet.

MC74LCX240

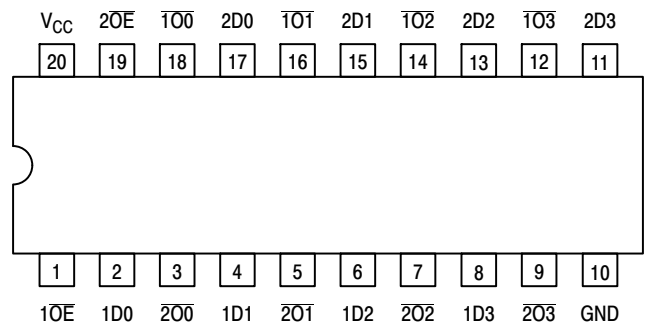


Figure 1. Pinout: 20-Lead (Top View)

PIN NAMES

Pins	Function
nOE	Output Enable Inputs
1Dn, 2Dn	Data Inputs
1On, 2On	3-State Outputs

TRUTH TABLE

Inputs		Outputs
1OE 2OE	1Dn 2Dn	1On, 2On
L	L	H
L	H	L
H	X	Z

H = High Voltage Level
L = Low Voltage Level
Z = High Impedance State
X = High or Low Voltage Level and Transitions
Are Acceptable; for I_{CC} reasons, DO NOT
FLOAT Inputs

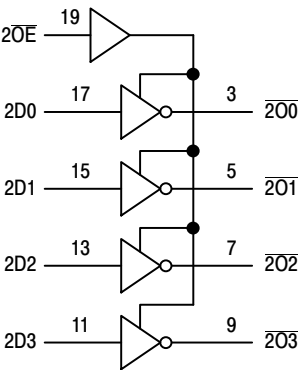
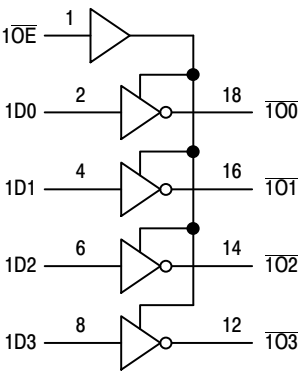


Figure 2. LOGIC DIAGRAM

MC74LCX240

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage	–0.5 to +6.5	V
V_I	DC Input Voltage (Note 1)	–0.5 to +6.5	V
V_O	DC Output Voltage (Note 1) Active-Mode (High or Low State)	–0.5 to $V_{CC} + 0.5$	V
	Tri-State Mode	–0.5 to +6.5	
	Power-Down Mode ($V_{CC} = 0$ V)	–0.5 to +6.5	
I_{IK}	DC Input Diode Current $V_{IN} < GND$	–50	mA
I_{OK}	DC Output Diode Current $V_{OUT} < GND$	–50	mA
I_O	DC Output Source/Sink Current	±50	mA
I_{CC} or I_{GND}	DC Supply Current per Supply Pin or Ground Pin	±100	mA
T_{STG}	Storage Temperature Range	–65 to +150	°C
T_L	Lead Temperature, 1 mm from Case for 10 secs	260	°C
T_J	Junction Temperature Under Bias	+150	°C
θ_{JA}	Thermal Resistance (Note 2) SOIC-20W	96	°C/W
	WQFN20	99	
	QFN20	111	
	TSSOP-20	150	
P_D	Power Dissipation in Still Air SOIC-20W	1302	mW
	WQFN20	1256	
	QFN20	1127	
	TSSOP-20	833	
MSL	Moisture Sensitivity SOIC-20W All Other Packages	Level 3 Level 1	–
F_R	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	–
V_{ESD}	ESD Withstand Voltage (Note 3) Human Body Model	> 2000	V
	Charged Device Model	N/A	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I_O absolute maximum rating must be observed.
2. Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.
3. HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.

MC74LCX240

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Typ	Max	Unit
V _{CC}	Supply Voltage	Operating	1.65	3.3	5.5	V
		Data Retention Only	1.5	3.3	5.5	
V _I	Digital Input Voltage		0	–	5.5	V
V _O	Output Voltage	Active Mode (High or Low State)	0	–	V _{CC}	V
		Tri-State Mode	0	–	5.5	
		Power Down Mode (V _{CC} = 0 V)	0	–	5.5	
T _A	Operating Free-Air Temperature		–40	–	+125	°C
t _r , t _f	Input Rise or Fall Rate	V _{CC} = 1.65 V to 1.95 V	0	–	20	nS/V
		V _{CC} = 2.3 V to 2.7 V	0	–	20	
		V _I from 0.8 V to 2.0 V, V _{CC} = 3.0 V	0	–	10	
		V _{CC} = 4.5 V to 5.5 V	0	–	5	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

4. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$		$T_A = -40^\circ\text{C to } +125^\circ\text{C}$		Unit
				Min	Max	Min	Max	
V_{IH}	High-Level Input Voltage		1.65 to 1.95	$0.65 \times V_{CC}$		$0.65 \times V_{CC}$		V
			2.3 to 2.7	1.7		1.7		
			2.7 to 3.6	2.0		2.0		
			4.5 to 5.5	$0.7 \times V_{CC}$		$0.7 \times V_{CC}$		
V_{IL}	Low-Level Input Voltage		1.65 to 1.95		$0.35 \times V_{CC}$		$0.35 \times V_{CC}$	V
			2.3 to 2.7		0.7		0.7	
			2.7 to 3.6		0.8		0.8	
			4.5 to 5.5		$0.3 \times V_{CC}$		$0.3 \times V_{CC}$	
V_{OH}	High-Level Output Voltage	$V_I = V_{IH}$ or V_{IL}						V
		$I_{OH} = -100 \mu\text{A}$	1.65 to 5.5	$V_{CC} - 0.1$	–	$V_{CC} - 0.1$	–	
		$I_{OH} = -4 \text{ mA}$	1.65	1.2	–	1.2	–	
		$I_{OH} = -8 \text{ mA}$	2.3	1.8	–	1.8	–	
		$I_{OH} = -12 \text{ mA}$	2.7	2.2	–	2.2	–	
		$I_{OH} = -16 \text{ mA}$	3.0	2.4	–	2.4	–	
		$I_{OH} = -24 \text{ mA}$	3.0	2.2	–	2.2	–	
		$I_{OH} = -32 \text{ mA}$	4.5	3.8		3.8		
V_{OL}	Low-Level Output Voltage	$V_I = V_{IH}$ or V_{IL}						V
		$I_{OL} = 100 \mu\text{A}$	1.65 to 5.5	–	0.1	–	0.1	
		$I_{OL} = 4 \text{ mA}$	1.65	–	0.45	–	0.45	
		$I_{OL} = 8 \text{ mA}$	2.3	–	0.6	–	0.6	
		$I_{OL} = 12 \text{ mA}$	2.7	–	0.4	–	0.4	
		$I_{OL} = 16 \text{ mA}$	3.0	–	0.4	–	0.4	
		$I_{OL} = 24 \text{ mA}$	3.0	–	0.55	–	0.55	
		$I_{OL} = 32 \text{ mA}$	4.5		0.6		0.6	

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DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = -40 °C to +85 °C		T _A = -40 °C to +125 °C		Unit
				Min	Max	Min	Max	
I _I	Input Leakage Current	V _I = 0 to 5.5 V	3.6	–	±5.0	–	±5.0	μA
I _{OZ}	3-State Output Leakage Current	V _I = V _{IH} or V _{IL} , V _O = 0 V to 5.5 V	3.6	–	±5.0	–	±5.0	μA
I _{OFF}	Power Off Leakage Current	V _I = 5.5 V or V _O = 5.5 V	0	–	10	–	10	μA
I _{CC}	Quiescent Supply Current	V _I = 5.5 V or GND	3.6	–	10	–	10	μA
ΔI _{CC}	Increase in I _{CC} per Input	V _{IH} = V _{CC} – 0.6 V	2.3 to 3.6	–	500	–	500	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. These values of V_I are used to test DC electrical characteristics only.

AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Condition	V _{CC} (V)	T _A = -40 °C to +85 °C		T _A = -40 °C to +125 °C		Unit
				Min	Max	Min	Max	
t _{PLH} , t _{PHL}	Propagation Delay, D to O	See Figures 3 and 4	1.65 to 1.95	–	10.3	–	10.3	ns
			2.3 to 2.7	–	7.8	–	7.8	
			2.7	–	7.5	–	7.5	
			3.0 to 3.6	–	6.5	–	6.5	
			4.5 to 5.5	–	5.9	–	5.9	
t _{PZH} , t _{PZL}	Output Enable Time, OE to OE to O	See Figures 3 and 4	1.65 to 1.95	–	13.0	–	13.0	ns
			2.3 to 2.7	–	10.0	–	10.0	
			2.7	–	9.0	–	9.0	
			3.0 to 3.6	–	8.0	–	8.0	
			4.5 to 5.5	–	7.3	–	7.3	
t _{PHZ} , t _{PLZ}	Output Disable Time, OE to O	See Figures 3 and 4	1.65 to 1.95	–	11.0	–	11.0	ns
			2.3 to 2.7	–	8.4	–	8.4	
			2.7	–	8.0	–	8.0	
			3.0 to 3.6	–	7.0	–	7.0	
			4.5 to 5.5	–	6.0	–	6.0	
t _{OSHL} , t _{OSLH}	Output to Output Skew (Note 5)		1.65 to 1.95	–	–	–	–	ns
			2.3 to 2.7	–	–	–	–	
			2.7	–	–	–	–	
			3.0 to 3.6	–	1.0	–	1.0	

6. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

MC74LCX240

DYNAMIC SWITCHING CHARACTERISTICS

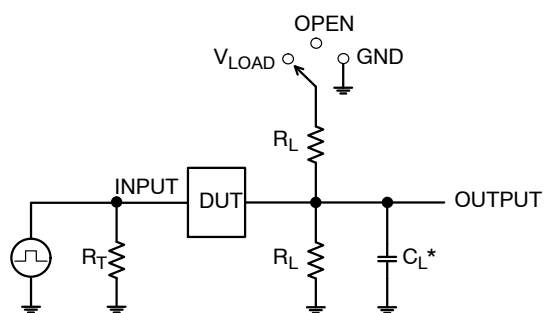
Symbol	Characteristic	Condition	T _A = +25 °C			Unit
			Min	Typ	Max	
V _{OLP}	Dynamic LOW Peak Voltage (Note 7)	V _{CC} = 3.3 V, C _L = 50 pF, V _{IH} = 3.3 V, V _{IL} = 0 V		0.8		V
V _{OLV}	Dynamic LOW Valley Voltage (Note 7)	V _{CC} = 3.3 V, C _L = 50 pF, V _{IH} = 3.3 V, V _{IL} = 0 V		0.8		V

7. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typ	Unit
C _{IN}	Input Capacitance	V _{CC} = 3.3 V, V _I = 0 V or V _{CC}	7	pF
C _{OUT}	Output Capacitance	V _{CC} = 3.3 V, V _I = 0 V or V _{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	10 MHz, V _{CC} = 3.3 V, V _I = 0 V or V _{CC}	25	pF

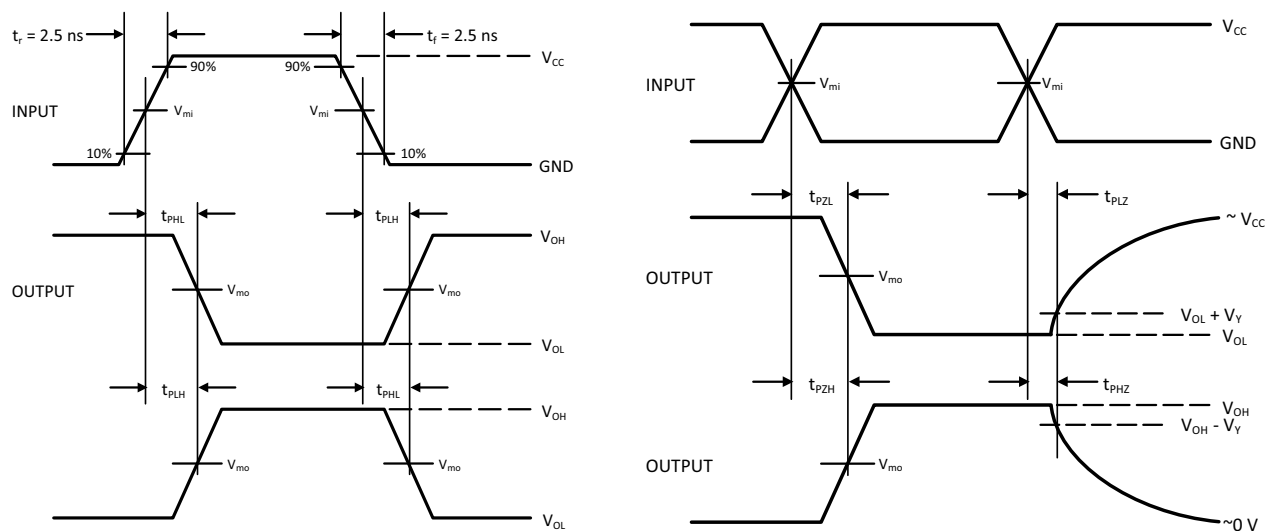
MC74LCX240



C_L includes probe and jig capacitance
 R_T is Z_{OUT} of pulse generator (typically 50 Ω)
 $f = 1$ MHz

Test	Switch Position
t_{PLH} / t_{PHL}	Open
t_{PLZ} / t_{PZL}	V_{LOAD}
t_{PHZ} / t_{PZH}	GND

Figure 3. Test Circuit



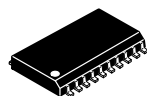
V_{CC} , V	R_L , Ω	C_L , pF	V_{LOAD}	V_{mi} , V	V_{mo} , V	V_Y , V
1.65 to 1.95	500	30	$2 \times V_{CC}$	$V_{CC}/2$	$V_{CC}/2$	0.15
2.3 to 2.7	500	30	$2 \times V_{CC}$	$V_{CC}/2$	$V_{CC}/2$	0.15
2.7	500	50	6 V	1.5	$V_{CC}/2$	0.3
3.0 to 3.6	500	50	6 V	1.5	$V_{CC}/2$	0.3
4.5 to 4.5	500	50	$2 \times V_{CC}$	$V_{CC}/2$	$V_{CC}/2$	0.3

Figure 4. Switching Waveforms

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
MC74LCX240DTR2G	LCX 240	TSSOP-20 (Pb-Free)	2500 Tape & Reel
MC74LCX240DWR2G	LCX240	SOIC-20 WB (Pb-Free)	1000 Tape & Reel

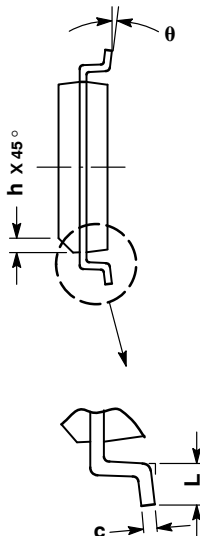
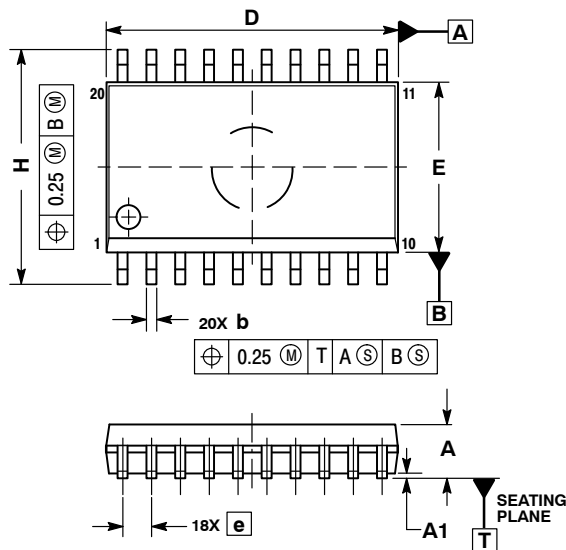
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).



SCALE 1:1

SOIC-20 WB
CASE 751D-05
ISSUE H

DATE 22 APR 2015

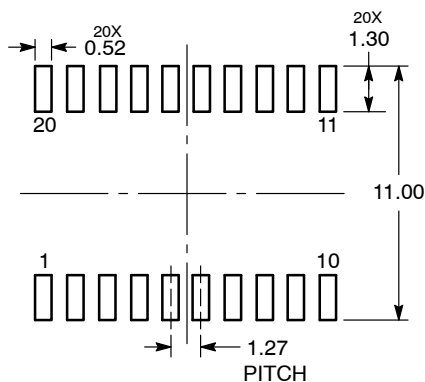


NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS	
	MIN	MAX
A	2.35	2.65
A1	0.10	0.25
b	0.35	0.49
c	0.23	0.32
D	12.65	12.95
E	7.40	7.60
e	1.27 BSC	
H	10.05	10.55
h	0.25	0.75
L	0.50	0.90
θ	0°	7°

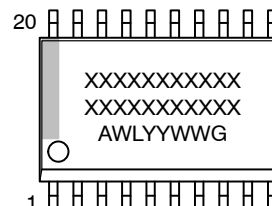
RECOMMENDED
SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC
MARKING DIAGRAM*

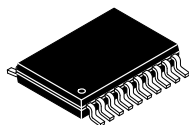


XXXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week
G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

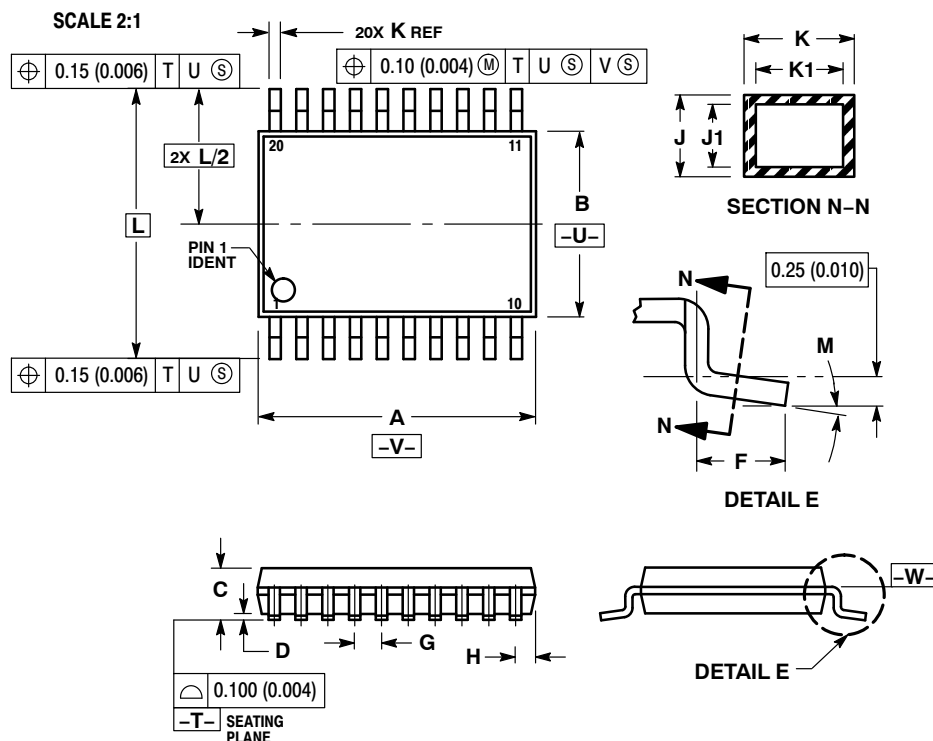
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TSSOP-20 WB
CASE 948E
ISSUE D

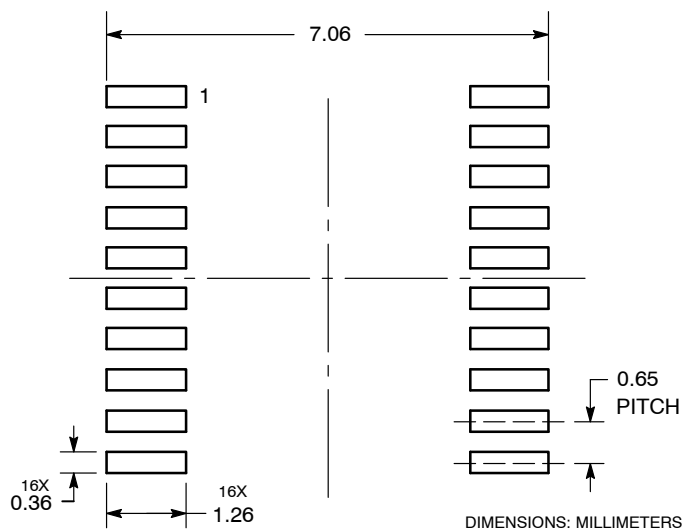
DATE 17 FEB 2016



- NOTES:**
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER
 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
 6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

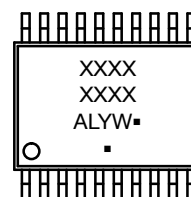
	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	6.40	6.60	0.252	0.260
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.27	0.37	0.011	0.015
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual. SOLDERRM/D.

GENERIC MARKING DIAGRAM*



A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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